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Vishay/Siliconix SI9100DJ02-E3

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Datasheet of SI9100DJ02-E3 - IC REG MULT CONFIG INV ISO 14DIP

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End of Life. Last Available Purchase Date is 31-Dec-2014

Si9100

Vishay Siliconix

3-W High-Voltage Switchmode Regulator

FEATURES

- 10- to 70-V Input Range
- Current-Mode Control
- On-Chip 150-V, 5-Ω MOSFET Switch
- Reference Selection Si9100 – ±1%
- High Efficiency Operation (> 80%)
- Internal Start-Up Circuit
- Internal Oscillator (1 MHz)
- SHUTDOWN and RESET

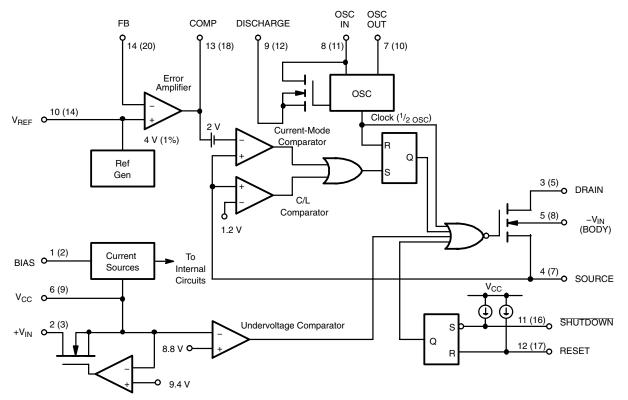
DESCRIPTION

The Si9100 high-voltage switchmode regulators are monolithic BiC/DMOS integrated circuits which contain most of the components necessary to implement high-efficiency dc-to-dc converters up to 3 watts. They can either be operated from a low-voltage dc supply, or directly from a 10- to 70-V unregulated dc power source. The Si9100 may be used with an appropriate transformer to implement most single-ended isolated power converter topologies (i.e., flyback and forward),

or by using a level shift circuit can generate a +5-V or a -5-V non-isolated output from a -48-V source.

The Si9100 is available in both standard and lead (Pb)-free 14-pin plastic DIP and 20-pin PLCC packages which are specified to operate over the industrial temperature range of $-40\,^{\circ}$ C to $85\,^{\circ}$ C.

FUNCTIONAL BLOCK DIAGRAM



Note: Figures in parenthesis represent pin numbers for 20-pin package.

Applications information, see AN702 and AN713.

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ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to $-V_{IN}$ ($V_{CC} < +V_{IN} + 0.3 \text{ V}$)	
V _{CC}	15 V
+V _{IN}	70 V
V _{DS}	150 V
I_D (Peak) (Note: 300 μs pulse, 2% duty cycle)	2.5 A
I _D (rms)	350 mA
Logic Inputs (RESET,	
SHUTDOWN, OSC IN)	–0.3 V to V_{CC} + 0.3 V
Linear Inputs (FEEDBACK, SOURCE)	–0.3 V to 7 V
HV Pre-Regulator Input Current (continuous)	3 mA
Storage Temperature	65 to 125°C
Operating Temperature	–40 to 85°C

Junction Temperature (T _J)
Power Dissipation (Package) ^a
14-Pin Plastic DIP (J Suffix) ^b
20-Pin PLCC (N Suffix) ^c
Thermal Impedance (Θ_{JA})
14-Pin Plastic DIP
20-Pin PLCC

Notes

- a. Device mounted with all leads soldered or welded to PC board.
- b. Derate 6 mW/°C above 25°C
- c. Derate 11.2 mW/°C above 25°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE

Voltages Referenced to -V _{IN}	
V _{CC}	R $_{\text{OSC}}$
+V _{IN}	Linear Inputs 0 to 7 V
f _{OSC}	Digital Inputs

SPECIFICATIONS ^a							
		Test Conditions UnlessOtherwise Specified			Limits		
Parameter	Symbol	DISCHARGE = $-V_{IN}$ = 0 V V_{CC} = 10 V, $+V_{IN}$ = 48 V R_{BIAS} = 390 k Ω , R_{OSC} = 330 k Ω	Temp ^b	Min ^c	Typ ^d	Max ^c	Unit
Reference							
Output Voltage	V _R	OSC IN = $-V_{IN}$ (OSC Disabled), $R_L = 10 \text{ M}\Omega$	Room	3.92	4.0	4.08	V
Output Impedancee	Z _{OUT}		Room	15	30	45	kΩ
Short Circuit Current	I _{SREF}	V _{REF} = -V _{IN}	Room	70	100	130	μА
Temperature Stability ^e	T _{REF}		Full		0.5	1.0	mV/°C
Oscillator							
Maximum Frequencye	f _{MAX}	R _{OSC} = 0	Room	1	3		MHz
Initial Accuracy	_	R _{OSC} = 330 kΩ, See Note f	Room	80	100	120	kHz
	fosc	R _{OSC} = 150 kΩ, See Note f	Room	160	200	240	
Voltage Stability	Δf/f	$\Delta f/f = f(13.5 \text{ V}) - f, (9.5 \text{ V})/f(9.5 \text{ V})$	Room		10	15	%
Temperature Coefficiente	T _{OSC}		Full		200	500	ppm/°C
Error Amplifier	•				•		•
Feedback Input Voltage	V _{FB}	FB Tied to COMP OSC In = -V _{IN} (OSC Disabled)	Room	3.96	4.00	4.04	V
Input BIAS Current	I _{FB}	OSC IN = -V _{IN} , V _{FB} = 4 V	Room		25	500	nA
Input OFFSET Voltage	Vos		Room		± 15	± 40	mV
Open Loop Voltage Gaine	A _{VOL}		Room	60	80		dB
Unity Gain Bandwidthe	BW	OSC IN = - V _{IN} , (OSC Disabled)	Room		1		MHz
Dynamic Output Impedancee	Z _{OUT}		Room		1000	2000	Ω
		SOURCE (V _{FB} = 3.4 V)	Room		-2.0	-1.4	
Output Current	louт	SINK (V _{FB} = 4.5 V)	Room	0.12	0.15		mA
Power Supply Rejection	PSRR	OSC IN = - V _{IN} , (OSC Disabled)	Room	50	70		dB



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		Test Conditions UnlessOtherwise Specified			Limits		
Parameter	Symbol	DISCHARGE = $-V_{\text{IN}}$ = 0 V V_{CC} = 10 V, $+V_{\text{IN}}$ = 48 V R_{BIAS} = 390 k Ω , R_{OSC} = 330 k Ω	Temp ^b	Min ^c	Typ ^d	Max ^c	Unit
Current Limit	1		·	ı	I	l l	
Threshold Voltage	V _{SOURCE}	R_L = 100 Ω from DRAIN to V_{CC} V_{FB} = 0 V	Room	1.0	1.2	1.4	V
Delay to Outpute	t _d	R_L = 100 Ω from DRAIN to V_{CC} V_{SOURCE} = 1.5 V, See Figure 1	Room		100	200	ns
Pre-Regulator/Start-Up							
Input Voltage	+V _{IN}	$I_{IN} = 10 \mu A$	Room			70	V
Input Leakage Current	+I _{IN}	$V_{CC} \ge 10 \text{ V}$	Room			10	μΑ
Pre-Regulator Start-Up Current	ISTART	Pulse Width≤300 μs V _{CC} = V _{UVLO}	Room	8	15		mA
V _{CC} Pre-Regulator Turn-Off Threshold Voltage	V _{REG}	I _{PRE-REGULATOR} = 10 μA	Room	7.8	9.4	9.7	
Undervoltage Lockout	V _{UVLO}	R_L = 100 Ω from DRAIN to V_{CC} See Detailed Description	Room	7.0	8.8	9.2	V
V _{REG} -V _{UVLO}	V _{DELTA}		Room	0.3	0.6		
Supply							
Supply Current	I _{CC}		Room	0.45	0.6	1.0	mA
Bias Current	I _{BIAS}		Room	10	15	20	μΑ
Logic							
SHUTDOWN Delaye	t _{SD}	V _{SOURCE} = -V _{IN} , See Figure 2	Room		50	100	
SHUTDOWN Pulse Widthe	t _{SW}		Room	50			
RESET Pulse Widthe	t _{RW}	See Figure 3	Room	50			ns
Latching Pulse Widthe SHUTDOWN and RESET Low	t _{LW}		Room	25			
Input Low Voltage	V _{IL}		Room			2.0	V
Input High Voltage	V _{IH}		Room	8.0			V
Input Current, Input Voltage High	I _{IH}	V _{IN} = 10 V	Room		1	5	μΑ
Input Current, Input Voltage Low	l _{IL}	V _{IN} = 0 V	Room	-35	-25		μΛ
MOSFET Switch							
Breakdown Voltage	V _{(BR)DSS}	$V_{SOURCE} = \overline{SHUTDOWN} = 0 \text{ V}$ $I_{DRAIN} = 100 \mu\text{A}$	Full	150	180		V
Drain-Source On Resistance ⁹	r _{DS(on)}	V _{SOURCE} = 0 V, I _{DRAIN} = 100 mA	Room		3	5	Ω
Drain Off Leakage Current	I _{DSS}	V _{SOURCE} = SHUTDOWN = 0 V V _{DRAIN} = 100 V	Room			10	μΑ
Drain Capacitance	C _{DS}	V _{SOURCE} = SHUTDOWN = 0 V	Room		35		pF

Notes

- Refer to PROCESS OPTION FLOWCHART for additional information. Room = 25°C, Full = as determined by the operating temperature suffix. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing. Guaranteed by design, not subject to production test. C_{STRAY} Pin 8 = \leq 5 pF Temperature coefficient of $r_{DS(on)}$ is 0.75% per °C, typical.

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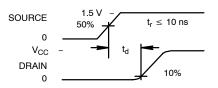


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TIMING WAVEFORMS



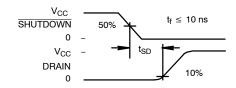


FIGURE 1. FIGURE 2.

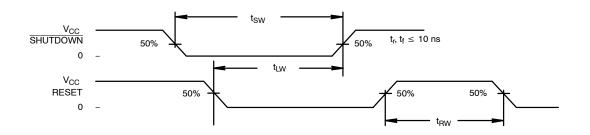
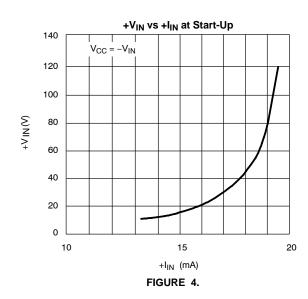
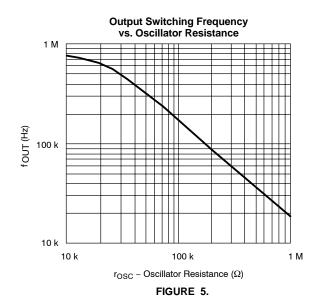


FIGURE 3.

TYPICAL CHARACTERISTICS





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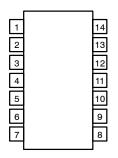


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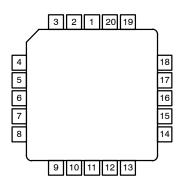
PIN CONFIGURATIONS

PDIP-14



Top View

PLCC-20



Top View

PIN DESCRIPTION				
	Pin			
Function	14-Pin DIP	20-Pin PLCC*		
BIAS	1	2		
+V _{IN}	2	3		
DRAIN	3	5		
SOURCE	4	7		
-V _{IN}	5	8		
V _{CC}	6	9		
OSC OUT	7	10		
OSC IN	8	11		
DISCHARGE	9	12		
V _{REF}	10	14		
SHUTDOWN	11	16		
RESET	12	17		
COMP	13	18		
FB	14	20		

ORDERING INFORMATION					
Standard Lead (Pb)-Free Temperature Part Number Range Package					
Si9100DJ02	Si9100DJ02—E3	–40 to 85 °C	PDIP-14		
Si9100DN02	Si9100DN02—E3	-40 to 65 C	PLCC-20		

DETAILED DESCRIPTION

Pre-Regulator/Start-Up Section

Due to the low quiescent current requirement of the Si9100 control circuitry, bias power can be supplied from the unregulated input power source, from an external regulated low-voltage supply, or from an auxiliary "bootstrap" winding on the output inductor or transformer.

When power is first applied during start-up, $+V_{IN}$ will draw a constant current. The magnitude of this current is determined by a high-voltage depletion MOSFET device which is connected between $+V_{IN}$ and V_{CC} . This start-up circuitry provides initial power to the IC by charging an external bypass capacitance connected to the V_{CC} pin. The constant current is

disabled when V $_{\rm CC}$ exceeds 9.4 V. If V $_{\rm CC}$ is not forced to exceed the 9.4-V threshold, then V $_{\rm CC}$ will be regulated to a nominal value of 9.4 V by the pre-regulator circuit.

As the supply voltage rises toward the normal operating conditions, an internal undervoltage (UV) lockout circuit keeps the output MOSFET disabled until V_{CC} exceeds the undervoltage lockout threshold (typically 8.8 V). This guarantees that the control logic will be functioning properly and that sufficient gate drive voltage is available before the MOSFET turns on. The design of the IC is such that the undervoltage lockout threshold will not exceed the pre-regulator turn-off voltage. Power dissipation can be minimized by providing an external power source to V_{CC} such that the constant current source is always disabled.

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DETAILED DESCRIPTION (CONT'D)

Note: During start-up or when V_{CC} drops below 9.4 V the start-up circuit is capable of sourcing up to 20 mA. This may lead to a high level of power dissipation in the IC (for a 48-V input, approximately 1 W). Excessive start-up time caused by external loading of the V_{CC} supply can result in device damage. Figure 4 gives the typical pre-regulator current at start-up as a function of input voltage.

BIAS

To properly set the bias for the Si9100, a 390-k Ω resistor should be tied from BIAS to $-V_{IN}$. This determines the magnitude of bias current in all of the analog sections and the pull-up current for the $\overline{SHUTDOWN}$ and RESET pins. The current flowing in the bias resistor is nominally 15 μ A.

Reference Section

The reference section of the Si9100 consists of a temperature compensated buried zener and trimmable divider network. The output of the reference section is connected internally to the non-inverting input of the error amplifier. Nominal reference output voltage is 4 V. During the reference trimming procedure the error amplifier is connected for unity gain in order to compensate for the input offset voltage in the error amplifier.

The output impedance of the reference section has been purposely made high so that a low impedance external voltage source can be used to override the internal voltage source, if desired, without otherwise altering the performance of the device.

Error Amplifier

Closed-loop regulation is provided by the error amplifier, which is intended for use with "around-the-amplifier" compensation. A MOS differential input stage provides for low input leakage current. The noninverting input to the error amplifier (V_{REF}) is internally connected to the output of the reference supply and should be bypassed with a small capacitor to ground.

Oscillator Section

The oscillator consists of a ring of CMOS inverters, capacitors, and a capacitor discharge switch. Frequency is set by an

external resistor between the OSC IN and OSC OUT pins. (See Figure 5 for details of resistor value vs. frequency.) The DISCHARGE pin should be tied to $-V_{IN}$ for normal internal oscillator operation. A frequency divider in the logic section limits switch duty cycle to $\leq 50\%$ by locking the switching frequency to one half of the oscillator frequency.

Remote synchronization is accomplished by capacitive coupling of a positive SYNC pulse into the OSC IN terminal. For a 5-V pulse amplitude and 0.5- μ s pulse width, typical values would be 100 pF in series with 3 k Ω to OSC IN.

SHUTDOWN and RESET

SHUTDOWN and RESET are intended for overriding the output MOSFET switch via external control logic. The two inputs are fed through a latch preceding the output switch. Depending on the logic state of RESET, SHUTDOWN can be either a latched or unlatched input. The output is off whenever SHUTDOWN is low. By simultaneously having SHUTDOWN and RESET low, the latch is set and SHUTDOWN has no effect until RESET goes high. The truth table for these inputs is given in Table 1.

Both pins have internal current source pull-ups and should be left disconnected when not in use. An added feature of the current sources is the ability to connect a capacitor and an open-collector driver to the SHUTDOWN or RESET pins to provide variable shutdown time.

Table 1. Truth Table for the SHUTDOWN and RESET Pins

SHUTDOWN	RESET	Output
Н	Н	Normal Operation
Н	1	Normal Operation (No Change)
L	Н	Off (Not Latched)
L	L	Off (Latched)
ı	L	Off (Latched, No Change)

Output Switch

The output switch is a 5- Ω , 150-V lateral DMOS device. Like discrete MOSFETs, the switch contains an intrinsic body-drain diode. However, the body contact in the Si9100 is connected internally to $-V_{IN}$ and is independent of the SOURCE.





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APPLICATIONS

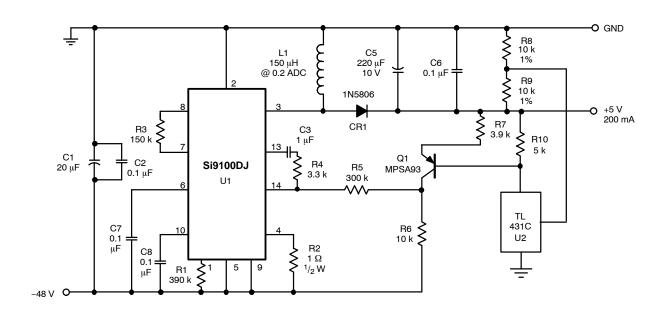


FIGURE 6. Buck-Boost, Non-Isolated 1-W Supply

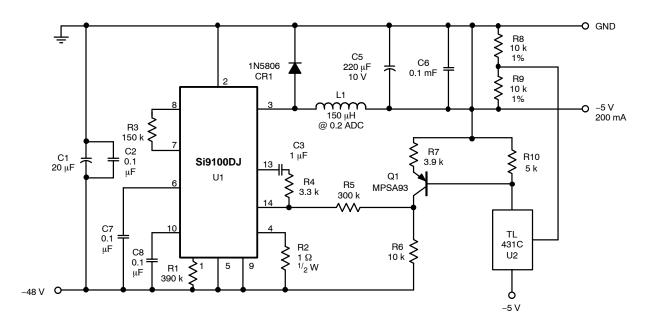


FIGURE 7. Non-Isolated 1-W Supply (Buck)

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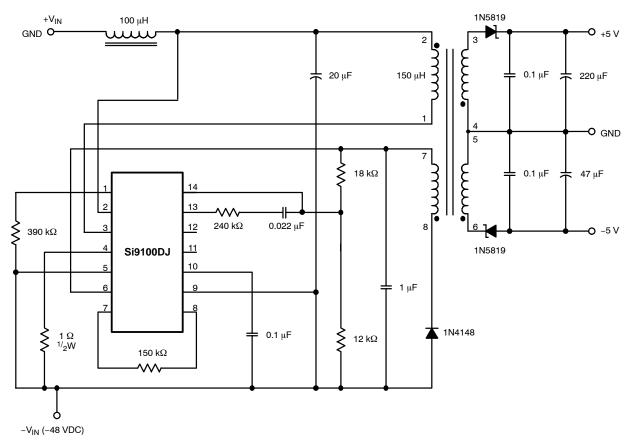


FIGURE 8. 1-W Flyback Converter for Telecommunications Power Supplies*

 $^{\star} \ \ \text{For additional information on using the Si9100 in telecommunications and ISDN power supplies, see AN713 and AN702.}$

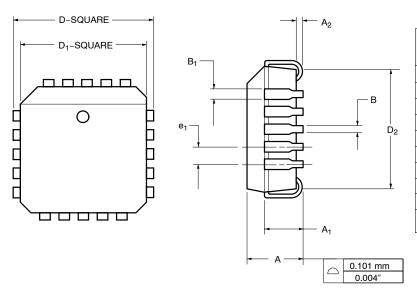
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Package Information Vishay Siliconix

PLCC: 20-LEAD (POWER IC ONLY)



	MILLIMETERS		INC	HES
Dim	Min	Max	Min	Max
Α	4.20	4.57	0.165	0.180
A ₁	2.29	3.04	0.090	0.120
A ₂	0.51	=	0.020	-
В	0.331	0.553	0.013	0.021
B ₁	0.661	0.812	0.026	0.032
D	9.78	10.03	0.385	0.395
D ₁	8.890	9.042	0.350	0.356
D_2	7.37	8.38	0.290	0.330
e ₁	1.27	BSC	0.050	BSC
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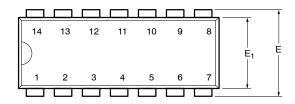
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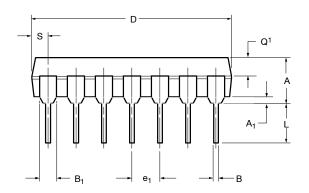


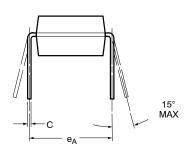


Package Information Vishay Siliconix

PDIP: 14-LEAD (POWER IC ONLY)







	MILLIMETERS		INC	HES	
Dim	Min	Max	Min	Max	
Α	3.81	5.08	0.150	0.200	
A ₁	0.38	1.27	0.015	0.050	
В	0.38	0.51	0.015	0.020	
B ₁	0.89	1.65	0.035	0.065	
С	0.20	0.30	0.008	0.012	
D	17.27	19.30	0.680	0.760	
E	7.62	8.26	0.300	0.325	
E ₁	5.59	7.11	0.220	0.280	
e ₁	2.29	2.79	0.090	0.110	
e _A	7.37	7.87	0.290	0.310	
L	2.79	3.81	0.110	0.150	
Q ₁	1.27	2.03	0.050	0.080	
S	1.02	2.03	0.040	0.080	
	ECN: S-40081—Rev. A, 02-Feb-04 DWG: 5919				

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